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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/721,999	11/26/2003	Naoya Watanabe	67161-111	. 6533
7590 06/14/2005 McDermott, Will & Emery 600 13th Street, N.W.			EXAMINER	
			YOHA, CONNIE C	
	C 20005-3096		ART UNIT	PAPER NUMBER
			2827	

DATE MAILED: 06/14/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	$\overline{}$
	10/721,999	WATANABE, NAOYA	
Office Action Summary	Examiner	Art Unit	\bigcup
•	Connie C. Yoha	2827	
The MAILING DATE of this communication Period for Reply	n appears on the cover sheet wit	th the correspondence address	
A SHORTENED STATUTORY PERIOD FOR FOR THE MAILING DATE OF THIS COMMUNICAT - Extensions of time may be available under the provisions of 37 Countries after SIX (6) MONTHS from the mailing date of this communication of the period for reply specified above is less than thirty (30) days of the period for reply is specified above, the maximum statutory Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON. FR 1.136(a). In no event, however, may a recon. , a reply within the statutory minimum of thirty period will apply and will expire SIX (6) MON statute, cause the application to become AB.	eply be timely filed (30) days will be considered timely. FHS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on	26 November 2003.		
2a) This action is FINAL . 2b) ⊠	This action is non-final.		
3) Since this application is in condition for all closed in accordance with the practice un	· ·	·	
Disposition of Claims		•	
4)⊠ Claim(s) <u>1-7</u> is/are pending in the applica	tion.		
4a) Of the above claim(s) is/are with			
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-7</u> is/are rejected.			·
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction a	and/or election requirement.		
Application Papers			
9) The specification is objected to by the Exa	aminer.		
10) The drawing(s) filed on 26 November 200		objected to by the Examiner.	
Applicant may not request that any objection to			
Replacement drawing sheet(s) including the o	* · · ·	·	
11) The oath or declaration is objected to by t	,		
Priority under 35 U.S.C. § 119			
12)⊠ Acknowledgment is made of a claim for fo a)⊠ All b)□ Some * c)□ None of:	reign priority under 35 U.S.C. §	119(a)-(d) or (f).	
 Certified copies of the priority docu 			
2. Certified copies of the priority docu			
3. Copies of the certified copies of the	· ·	received in this National Stage	
application from the International B			
* See the attached detailed Office action for	a list of the certified copies not	received.	
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Attachment(s)	PHIMARY E	AMENEH	
1) Motice of References Cited (PTO-892)		ummary (PTO-413)	
 Notice of Draftsperson's Patent Drawing Review (PTO-943) Anformation Disclosure Statement(s) (PTO-1449 or PTO/5 Paper No(s)/Mail Date 11/26/03.)/Mail Date formal Patent Application (PTO-152) ·	
C. Potent and Trademork Office			

Application/Control Number: 10/721,999

Art Unit: 2827

DETAILED ACTION

Page 2

This office acknowledges receipt of the following items from the Applicant:
 Papers submitted under 35 U.S.C. 119(a)-(d) have been placed of record in the

file.

Information Disclosure Statement (IDS) filed on 11/26/03 was considered.

2. Claims 1-7 are presented for examination.

Claim Objections

3. Claim 1 is objected to because the limitation defining the variable N and M are defined prior to the variable being used causing confusion. Applicant is required to cancel the claim(s), or amend the claim(s) to place the claim(s) in proper form.

Claim Rejections - 35 USC ∋ 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 1-7 are rejected under 35 U.S.C. 102(e) as being anticipated by Watanabe et al, Pat. No. 6888776 (cited IDS).

With regard to claim 1, Watanable discloses a memory device comprising a plurality of memory banks (fig. 79, BA#1, BA#0) each having rows that can be activated independently of another memory bank (col. 1, line 57-60), wherein where N is a natural number equal to or greater than

Art Unit: 2827

two and equal to or smaller than N-1 (fig. 79), a first memory bank (fig. 79, BA#) of said plurality of memory banks includes first to N-th sub-memory blocks (fig. 79, SMA0-SMA3), an M-th sub-memory block (fig. 80, MB0-MB7) of said first to N-th sub-memory blocks includes a first memory cell array (fig. 34, MB0) including a plurality of memory cells arranged in rows and columns (col. 48, line 59-61) and a first local control circuit (fig. 35, LOCT0-11), in a refresh mode, starting an operation of successively selecting rows of said first memory cell array in response to a first refresh end signal received from an (M-1)th sub-memory block and instructing a refresh start to an (M+1)th sub-memory block when said operation of successively selecting rows ends (col. 11, line 27-35) (col. 51, line 47-63), and said first memory bank further includes a plurality of sense amplifier bands (fig. 80, SAB0) each shared by adjacent two of said first to N-th sub memory blocks (col. 2, line 7-16).

With regard to claim 2, Watanable discloses wherein each of said first to N-the sub-memory blocks (fig. 34, SMA) includes a plurality of word lines for performing row selection for a memory cell (fig. 34, WL), said semiconductor memory device further comprising: an address counter (fig. 34, 204) generating a refresh address for use in common in said first to N-th sub-memory blocks to select one of said plurality of word lines (col. 51, line 5-60); and an address bus (fig. 34, 206) transmitting said refresh address to said first to N-th sub-memory blocks.

With regard to claim 3 Watanable discloses wherein said M-th sub-memory block (fig. 34, MB0-MB11) includes first to K-th word lines (fig. 34, WL<511:0>) for performing row selection for a memory cell, where K is a natural number equal to or

Art Unit: 2827

greater than two, and said first local control circuit (fig. 35, LOCTO) includes a row address decoder (fig. 35, 240) activated in response to the first refresh end signal received from the (M-1) sub-memory block for decoding a refresh address to select one of said first to K-th word lines (col. 51, line 24-46) and refresh end diction circuit outputting a second refresh end signal to instruct a refresh start to said (M+1)th sub-memory block when said refresh address corresponds to a refresh end of said K-th word line (col. 11, line 27-35) (col. 51, line 47-63).

With regard to claim 4, Watanable discloses wherein said first sub-memory block includes a second memory cell (fig. 34, MB1) including a plurality of memory cells arranged in rows and column and a second local control circuit (fig. 35, LOCT1), in a refresh mode, starting an operation of successively selecting rows of said second memory cell array in response to a third refresh end signal received from the N-th sub-memory block and instructing a refresh start to a second sub-mmeory block when said operation of successively selecting rows of said second memory cell array ends (col. 11, line 27-35) (col. 50, line 12-42).

With regard to claim 5, Watanable discloses wherein said first local control circuit includes first refresh start control circuit inativated in response to a reset signal and activated in response to said first refresh end signal received from said (M-1)th submemory block for outputting a first refresh start signal (col. 50, line 12-42), and said second local control circuit includes a second refresh start control circuit activated in response to said reset signal and activated in response to said third refresh end signal

Art Unit: 2827

received from said N-th sub-mmeory block for outputting a second refresh start signal (col. 63, line 11-column 64, line 35) (col. 72, line 57-67).

With regard to claim 6, Watanable discloses memory device comprising a first memory block (fig. 79, BA#1) wherein said first memory block includes a plurality of sub-memory blocks (fig. 79, SMA0-SMA1) being refreshed in a circulating manner in a refresh mode (col. 11, line 27-35), each of plurality of sub-memory blocks (fig. 34, SMA) includes a memory cell array (fig. 34, MB0-MB11) including a plurality of memory cells (fig. 35, MC) arranged in rows and columns and a local control circuit (fig. 35, LOCT11) performing an operation of successively selecting rows of said memory cell array in response to an end of a refresh operation in a sub-mmeory block at a previous stage which precedes by one in refresh-circulating order of said plurality of sub-memory blocks (col. 11, line 27-35) (col. 51, line 47-63), and refresh cycle period in each of said plurality of memory blocks is determined depending on a number of said sub-memory blocks included in said first memory block (col. 72, line 27-36) (also with regard to claim 7).

Conclusion

5. The prior art made of record and not relied upon is considered pertinent to applicants' disclosure. Hidaka (6538953), Khang et al (6111808) and Aichelmann, Jr. et al (4172282) disclosed a memory device comprising plurality of blocks and banks having refresh operation.

Application/Control Number: 10/721,999 Page 6

Art Unit: 2827

6. When responding to the office action, Applicants= are advised to provide the examiner with the line numbers and page numbers in the application and/or references cited to assist the examiner to locate the appropriate paragraphs.

- 7. A shortened statutory period for response to this action is set to expire 3 (three) months and 0 (zero) day from the date of this letter. Failure to respond within the period for response will cause the application to become abandoned (see MPEP 710.02 (b)).
- 8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to whose telephone number is (571) 272-1799. The examiner can normally be reached on Mon. Fri. from 8:00 A.M. to 5:30 PM. The examiner's supervisor, David Nelms, can be reached at (571) 272-1787. The fax phone number for this Group is (703) 872-9306. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 305-0956.
- 9. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov should you have questions on access to the Private Pair system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Application/Control Number: 10/721,999

Art Unit: 2827

Page 7

C. Yoha

June 2003

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